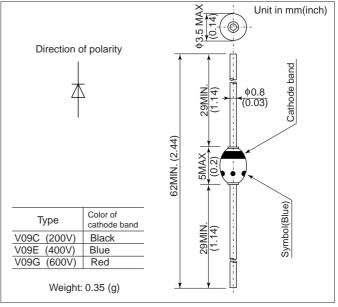


## FEATURES

- For high speed switching.
- Diffused-junction. Glass passivated and encapsulated.

### **OUTLINE DRAWING**



### **ABSOLUTE MAXIMUM RATINGS**

Items	Туре		V09C	V09E	V09G				
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	V	200	400	600				
Non-Repetitive Peak Reverse Voltage	V <sub>RSM</sub>	V	300	500	800				
Average Forward Current	I <sub>F(AV)</sub>	А	$0.8$ (Single-phase half sine wave $180^{\circ}$ conduction ) TL = 100°C, Lead length = 10mm )						
Surge(Non-Repetitive) Forward Current	I <sub>FSM</sub>	А	35(Without PIV, 10ms conduction, $Tj = 165^{\circ}C$ start )						
I <sup>2</sup> t Limit Value	l <sup>2</sup> t	A <sup>2</sup> s	4.9( Time = 2 ~ 10ms, I = RMS value )						
Operating Junction Temperature	Tj	°C	-65 ~ +165						
Storage Temperature	T <sub>stg</sub>	°C	-65 ~ +200						

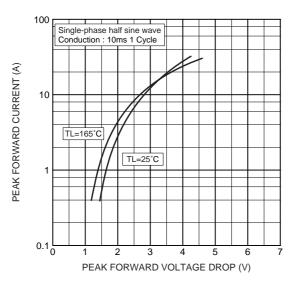
Notes (1) Lead mounting : Lead temperature 300°C max. to 3.2mm from body for 5sec. max.. (2) Mechanical strength : Bending 90°×2 cycles or 180°×1 cycle, Tensile 2kg, Twist 90°×1 cycle.

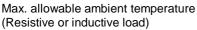
## CHARACTERISTICS(T<sub>L</sub>=25°C)

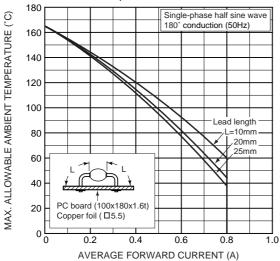
Items	Symbols	Units	Min.	Тур.	Max.	Test Conditions	
Peak Reverse Current	I <sub>RRM</sub>	μA	-	4.0	20	C class	Rated V <sub>RRM</sub>
				2.0	10	E,G class	
Peak Forward Voltage	V <sub>FM</sub>	V	_	_	1.6	$I_{FM}$ =0.8 Ap, Single-phase half sine wave 1 cycle	
Reverse Recovery Time	trr	μs	_	_	0.4	I <sub>F</sub> =2mA, V <sub>R</sub> =-15V	
Steady State Thermal Impedance	R <sub>th(j-a)</sub>	°C/W	_	-	80	- Lead length = 10 mm	
	R <sub>th(j-l)</sub>				50		

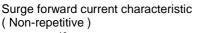
# V09

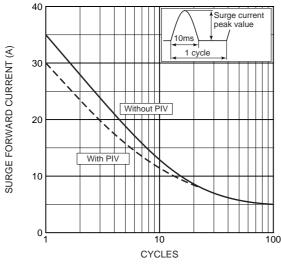
#### Forward characteristics



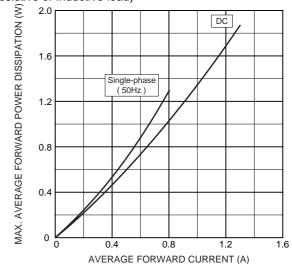




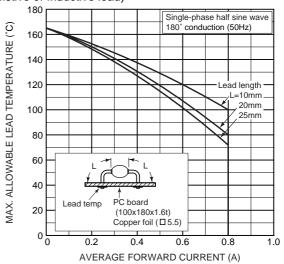




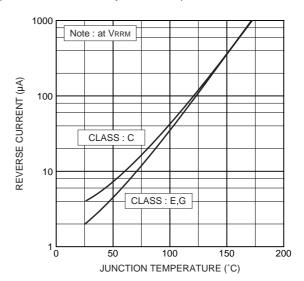
Max. average forward power dissipation (Resistive or inductive load)



Max. allowable lead temperature (Resistive or inductive load)

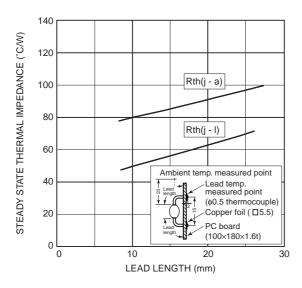


Typ. reverse current vs. junction temperature

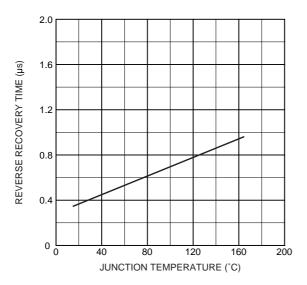


# V09

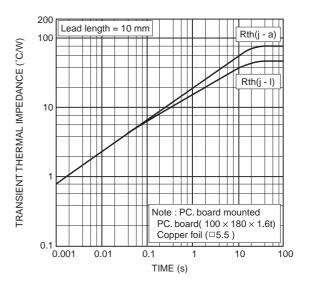
#### Steady state thermal impedance



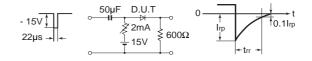
Typ. reverse recovery time vs. junction temperature



#### Transient thermal impedance



#### Reverse recovery time(trr) test circuit



# **HITACHI POWER SEMICONDUCTORS**

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